



**The Fourth Asian School-Conference on Physics and
Technology of Nanostructured Materials**

ASCO-NANOMAT 2018

PROGRAMME

Institute of Automation and Control Processes FEB RAS

Far Eastern Federal University

Vladivostok

2018

General information

Plenary talk – 40 minutes including questions

Ordinary talk – 15 minutes including questions

Coffee break – 15–20 minutes

Lunch – 90 minutes

Organizers

Institute of Automation and Control
Processes FEB RAS



Far Eastern Federal University



General sponsors

Russian Foundation for
Basic Research



Skolkovo Institute of Science and
Technology

Skoltech

Skolkovo Institute of Science and Technology

Official sponsors

LLC “MACRO GROUP”



Technoinfo Ltd.



Sunday, 23 September

- 09:00 – 18:00 Participants arrival at the airport of Vladivostok, transportation and accommodation
18:00 – 20:00 Participants registration in the hotel at FEFU campus

Monday, 24 September

- 08:00 – 08:30 Participants registration
08:30 – 08:50 Opening remarks
08:50 – 10:50 Plenary session
10:50 – 11:05 General sponsor talk
11:05 – 11:20 Coffee break
11:20 – 12:50 Physics of nanostructures and interfaces, self-organization processes
12:50 – 14:30 *Conference Photo and Lunch*
14:30 – 16:30 Plenary session
16:30 – 16:50 *Coffee break*
16:50 – 18:35 Physics of semiconducting nanostructures and heterostructures, including silicide, germanide and stannide heterostructures: experiment, calculations and technology
18:35 – 20:00 Poster session I
20:00 – 21:00 *Welcome party*

Tuesday, 25 September

- 09:00 – 10:20 Plenary session
10:20 – 10:40 *Coffee break*
10:40 – 12:25 4th group material's alloy based on Si, Ge, Sn & Pb, C: formation, structure and properties
12:25 – 14:00 *Lunch*
14:00 – 16:00 Plenary session
16:00 – 16:15 *Coffee break*
16:15 – 17:00 Official sponsor session
17:00 – 18:30 Optical materials and photonic crystals
18:30 – 18:50 *Coffee break*
18:30 – 20:00 Poster session II
20:30 – 23:00 *Excursion "Night Vladivostok"*

Wednesday, 26 September

- 09:00 – 12:00 Excursion to the Institute of Automation and Control Processes
FEB RAS
- 12:00 – 13:30 *Lunch (FEFU campus)*
- 13:30 – 19:00 Excursion “Voroshilov’s battery of Russky Island” and
“Primorsky Aquarium”

Thursday, 27 September

- 09:00 – 10:20 Plenary session
- 10:20 – 10:40 *Coffee break*
- 10:40 – 12:40 Nanostructured coverages, nanocomposites, functional hybrid
materials: formation, structure and properties
- 12:40 – 14:10 *Lunch*
- 14:10 – 15:30 Plenary session
- 15:30 – 17:15 Formation and properties of ferromagnetic and ferroelectric
materials, a spintronics optoelectronics and electromechanics
- 17:15 – 18:00 *Coffee break*
- 18:00 – 19:00 Award ceremony and closing remarks
- 19:30 – 21:30 *Symposium Dinner (Café of FEFU)*

Friday, 28 September

- 09:00 – 22:00 Participants departure

Programme of the Fourth Asian School-Conference on Physics and Technology of Nanostructured Materials ASCO-NANOMAT 2018

SUNDAY, 23 SEPTEMBER

- 09:00 – 18:00 Participants arrival at the airport of Vladivostok, transportation and accommodation
- 18:00 – 20:00 Participants registration in the hotel at FEFU campus

MONDAY, 24 SEPTEMBER

Participants registration **08:00 – 08:30**

Opening remarks **08:30 – 08:50**

Chairman: A.A. Saranin

Plenary session **08:50 – 10:50**

PS.24.01i **A.V. Dvurechenskii**, A.I. Yakimov, A.F. Zinovieva, A.V. Nenashev, V.V. Kirienko,
A.F. Bloshkin
Rzhanov Institute of Semiconductor Physics of SB RAS, Novosibirsk, Russia
Optical and spin phenomena in silicon based quantum dot
heterostructures

PS.24.02i F. Rovaris, R. Bergamaschini, **F. Montalenti**
L-NESS and Materials Science Department, University of Milano-Bicocca, Milano, Italy
Continuum modeling of semiconductor heteroepitaxial growth including
both elastic and plastic relaxation

PS.24.03i **D. Vyalikh**
*Donostia International Physics Center (DIPC), Departamento de Fisica de Materiales and
CFM-MPC UPV/EHU, San Sebastian, Spain*
ARPES insight into the exotic magnetism and strong electron
correlations at the surface and in the bulk of rare-earth intermetallics

General sponsor talk **10:50 – 11:05**

S.24.01o Skolkovo Institute of Science and Technology

Coffee break **11:05 – 11:20**

**Physics of nanostructures and interfaces,
self-organization processes**

Chairman: *F. Montalenti*

11:20 – 12:50

- I.24.01o **L.V. Bondarenko¹**, A.Y. Tupchaya¹, D.V. Gruznev^{1,2}, A.V. Zotov^{1,2,3},
A.A. Saranin^{1,2}
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
³*Vladivostok State University of Economics and Service, Vladivostok, Russia*
Atomic and electronic structure of Si(111)6x6-Au surface
- I.24.02o **H. Toyama¹**, H. Huang¹, T. Nakamura¹, L.V. Bondarenko², A.Y. Tupchaya²,
D.V. Gruznev², A. Takayama¹, A.V. Zotov^{2,3}, A.A. Saranin^{2,3}, S. Hasegawa¹
¹*Department of Physics, School of Science, University of Tokyo, Japan*
²*Institute of Automation and Control Processes, Vladivostok, Russia*
³*School of Natural Science, Far Eastern Federal University, Vladivostok, Russia*
Superconductivity of Pb ultrathin film on Ge(111) surface
- I.24.03o **I. Krasnikov¹**, A. Seteikin¹, B. Roth², M. Meinhardt-Wollweber²
¹*Amur State University, Blagoveschensk, Russia*
²*Hannover Centre for Optical Technologies, Leibniz University Hannover, Hannover, Germany*
Monte Carlo modeling of Raman scattering in multilayer turbid media
- I.24.04o **N.S. Saenko**, A.M. Ziatdinov
Institute of Chemistry FEB RAS, Vladivostok, Russia
Full-profile approximation of the X-ray diffraction pattern for nanographite powder including γ -band by taking into account a radial distribution of interatomic distances
- I.24.05o **I.A. Kibirev^{1,2}**, A.V. Matetskiy¹, A.V. Zotov^{1,2,3}, A.A. Saranin^{1,2}
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
³*Department of Electronics, Vladivostok State University of Economics and Service, Vladivostok, Russia*
Electronic topological transition in InSe thin films
- I.24.06o **P.D. Andriushchenko^{1,2}**, Y.A. Shevchenko^{1,2}, A.G. Makarov^{1,2}, K.V. Nefedev^{1,2}
¹*Far Eastern Federal University, Vladivostok, Russia*
²*Institute of Applied Mathematics of FEB RAS, Vladivostok, Russia*
The heat capacity of honeycomb lattice with long- and short-range interactions

Conference Photo and Lunch

12:50 – 14:30

Chairman: *A.V. Dvurechenskii*

Plenary session

14:30 – 16:30

- PS.24.04i **T. Suemasu**, R. Takabe, T. Deng, T. Sato, Z. Xu, Y. Yamashita, K. Kodama,
S. Matsuno, K. Toko
University of Tsukuba, Tsukuba, Japan
Present status and future prospect of BaSi₂ solar cells

- PS.24.05i **D.B. Migas**¹, V.O. Bogorodz¹, A.B. Filonov¹, A.Yu. Alexeev¹, V.E. Borisenko¹, N.V. Skorodumova^{2,3}
¹Belarusian State University of Informatics and Radioelectronics, Minsk, Belarus
²Multiscale Materials Modelling, Department of Materials and Engineering, Royal Institute of Technology (KTH), Stockholm, Sweden
³Department of Physics and Astronomy, Uppsala University, Uppsala, Sweden
 New 2D-like structures based on ultrathin Mg₂X (X = Si, Ge, Sn) films
- PS.24.06i **J. Kaplun**^{1,2}
¹Phononics Technology Inc., Israeli Center of Advanced Diamond Technologies, Hataasia 51 St., Nesher 3660102, Israel
²Dare Labs Consulting, Harav Kitroni 26/7, Petach Tiqwa, 4939029, Israel
 CVD diamond: the present and the future. Review

Coffee break

16:30 – 16:50

Physics of semiconducting nanostructures and heterostructures, including silicide, germanide and stannide heterostructures: experiment, calculations and technology

Chairman: V.Y. Nazarov

16:50 – 18:35

- III.24.01o **T. Deng**, T. Sato, Z. Xu, R. Takabe, S. Yachi, Y. Yamashita, K. Toko, T. Suemasu
 University of Tsukuba, Tsukuba, Japan
 Towards BaSi₂ homojunction solar cells on Si(001)
- III.24.02o **E.A. Chusovitin**¹, D.L. Goroshko^{1,2}, N.G. Galkin^{1,2}, S.V. Chusovitina¹, A.V. Tupkalo²
¹Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia
²Far Eastern Federal University, Vladivostok, Russia
 Si matrix charge state influence on photoresponse of Si layer with embedded β-FeSi₂ nanocrystals
- III.24.03o **Yu.V. Luniakov**
 Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia
 New phases of high pressure Mg₂Si: an extensive first principle structure search
- III.24.04o A.A. Spirina^{1,2}, A.G. Nastovjak¹, **N.L. Shwartz**^{1,2}
¹Rzhanov Institute of Semiconductor Physics of SB RAS, Novosibirsk, Russia
²Novosibirsk State Technical University, Novosibirsk, Russia
 Surface orientation influence on the characteristics of GaAs substrates high-temperature annealing
- III.24.05o **A.S. Tarasov**^{1,2}, I.A. Bondarev^{1,2}, M.V. Rautskii¹, A.V. Lukyanenko^{1,2}, D.A. Smolyakov¹, T.E. Smolyarova^{1,2}, I.A. Tarasov¹, S.N. Varnakov¹, S.G. Ovchinnikov^{1,2}, N.V. Volkov¹
¹Kirensky Institute of Physics, Federal Research Center KSC SB RAS, Krasnoyarsk, Russia
²Institute of Engineering Physics and Radio Electronics, Siberian Federal University, Krasnoyarsk, Russia
 Iron silicide hybrid structures: magnetoimpedance and spin accumulation effect

- III.24.06o **A.S. Gouralnik**¹, A.M. Maslov^{1,2}, A.V. Gerasimenko³
¹Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia
²Far Eastern Federal University, Vladivostok, Russia
³Institute of Chemistry FEB RAS, Vladivostok, Russia
Mg₂Si formation at high temperatures by pulse deposition of Mg onto Si(111)
- III.24.07o **I.A. Yakovlev**, B.A. Belyaev, S.N. Varnakov, S.G. Ovchinnikov
Kirensky Institute of Physics, Federal Research Center KSC SB RAS, Krasnoyarsk, Russia
The magnetic anisotropy of Fe₃Si synthesized at magnetic field by MBE

Poster session I **18:35 – 20:00**

Welcome party **20:00 – 21:00**

TUESDAY, 25 SEPTEMBER

Chairman: T. Suemasu

Plenary session

09:00 – 10:20

- PS.25.01i **V.A. Bykov**^{1,2}, A. Kalinin^{1,2}, V. Polyakov¹, A. Shelaev^{1,2}
¹*NT-MDT-Spectral Instruments Companies Group, www.ntmdt-si.com*
²*Moscow Institute of Physics and Technology*
Modern possibilities of scanning probe methods for complex analysis of surface
- PS.25.02i **S.A. Kukushkin**¹, A.V. Osipov¹, A.V. Luk'yanov²
¹*Institute of Problems of Mechanical Engineering of RAS (IPME RAS), St. Petersburg, Russia*
²*New Silicon Technologies Ltd., St. Petersburg, Russia*
Nano-assembly of SiC films on Si - a new method of growing low-defect epitaxial structures. Nanoscaled silicon carbide on silicon: a new bandgap material for micro- and optoelectronics

Coffee break

10:20 – 10:40

4th group material's alloy based on Si, Ge, Sn & Pb: formation, structure and properties

Chairman: D.B. Migas

10:40 – 12:25

- II.25.01o **H. Eguchi**, M. Iinuma, H. Hoshida, N. Murakoso, Y. Terai
Department of Computer Science and Electronics, Kyushu Institute of Technology, Fukuoka, Japan
Growth of Sb-doped β -FeSi₂ epitaxial films and optimization of donor activation conditions
- II.25.02o **A.E. Klimov**^{1,2}, A.N. Akimov¹, V.S. Epov¹, E.V. Fedosenko¹, D.V. Ishchenko¹, N.S. Paschin¹, V.N. Sherstyakova¹, O.E. Tereshchenko^{1,3}
¹*Rzhanov Institute of Semiconductor Physics of SB RAS, Novosibirsk, Russia*
²*Novosibirsk State Technical University, Novosibirsk, Russia*
³*Novosibirsk State University, Novosibirsk, Russia*
The effect of surface on conductivity of PbSnTe:In/BaF₂ topological crystalline insulator in space charge limited current regimes
- II.25.03o **H. Hoshida**¹, N. Murakoso¹, T. Suemasu², Y. Terai¹
¹*Department of Computer Science and Electronics, Kyushu Institute of Technology, Fukuoka, Japan*
²*Institute of Applied Physics, University of Tsukuba, Tsukuba, Japan*
Identification of Raman vibrational modes in BaSi₂ epitaxial film by depolarization ratio
- II.25.04o **S.G. Bobkov**^{1,2}
¹*Federal State-Funded Institution of Science Institute for Design Problems in Microelectronics of Russian Academy of Sciences (IPPM RAS) Moscow, Russian Federation*
²*Electronics Department, National Research Nuclear University «MEPhI» Moscow, Russian Federation*
High-performance microprocessors for industrial applications

- II.25.05o **I.A. Tambasov**¹, A.S. Voronin², N.P. Evsevskaya³, M.N. Volochaev^{1,4},
A.S. Aleksandrovsky¹, S.R. Abelian¹, E.V. Tambasova⁴
¹Kirensky Institute of Physics, Federal Research Center KSC SB RAS, Krasnoyarsk, Russia
²Federal Research Centre Krasnoyarsk Scientific Center of the Siberian Branch of Russian Academy of Sciences, Krasnoyarsk, Russia
³Institute of Chemistry and Chemical Technology, Federal Research Center KSC SB RAS, Krasnoyarsk, Russia
⁴Reshetnev Siberian State University of Science and Technology, Krasnoyarsk, Russia
Thermoelectric properties of optically transparent thin films based on single-walled carbon nanotubes
- II.25.06o **D.L. Goroshko**^{1,2}, E.Y. Subbotin¹, K.N. Galkin¹, S.A. Dotsenko^{1,2}, E.A. Chusovitin¹,
A.K. Gutakovskii^{3,4}, A.A. Usenko⁵, V.V. Khovailo⁵
¹Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia
²Far Eastern Federal University, Vladivostok, Russia
³Rzhanov Institute of Semiconductor Physics SB RAS, Novosibirsk, Russia
⁴Novosibirsk State University, Novosibirsk, Russia
⁵National University of Science and Technology, Moscow, Russia
Thermoelectric properties of nanostructured material based on Si and GaSb
- II.25.07o A. Paddubskaya¹, **P. Kuzhir**^{1,2}, A. Stepanov², G. Remnev², T. Kaplas³, Y. Svirko³
¹Institute for Nuclear Problems of Belarusian State University, Minsk, Belarus
²Tomsk Polytechnic University, Tomsk, Russia
³Institute of Photonics, University of Eastern Finland, Joensuu, Finland
Graphene based passive THz devices: impact of high intensity pulse ion beam

Lunch **12:25 – 14:00**

Chairman: S.A. Kukushkin

Plenary session **14:00 – 16:00**

- PS.25.03i **Y.K. Kim**
Department of Materials Science and Engineering, Korea University, Seoul 02841, Korea
Spin-orbit torque in nonmagnet-ferromagnet junctions
- PS.25.04i **X.F. Han**
Institute of Physics, University of Chinese Academy of Sciences, Chinese Academy of Sciences, Beijing, China
Magnon valve effect
- PS.25.05i **O.A. Tretiakov**^{1,2}
¹Institute for Materials Research, Tohoku University, Sendai, Japan
²School of Physics, The University of New South Wales Sydney NSW 2052, Australia
Skyrmionics in ferromagnets and antiferromagnets

Coffee break **16:00 – 16:15**

Chairman: N.G. Galkin

Official sponsor`s session **16:15 – 17:00**

- S.25.01o LLC “MACRO GROUP”
- S.25.02o Technoinfo Ltd.

Optical materials and photonic crystals**17:00 – 18:30**

- V.25.01o **A.A. Sergeev^{1,2}**, K.A. Sergeeva², A.A. Leonov^{1,2}, I.V. Postnova²,
S.S. Voznesenskiy^{1,2}, Yu.N. Kulchin^{1,2}
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
Manganese-doped zinc sulfide quantum dots for methane detection in aqueous media
- V.25.02o A.E. Nazirov¹, A.V. Pestov², E.B. Modin¹, Yu.O. Privar¹, **A.Yu. Mironenko¹**,
S.Yu. Bratskaya¹
¹*Institute of Chemistry FEB RAS, Vladivostok, Russia*
²*I. Ya. Postovsky Institute of Organic Synthesis, Ural Branch of RAS, Yekaterinburg, Russia*
Ligand-assisted synthesis of ZnSe quantum dots in solutions of carboxyalkyl chitosan derivative
- V.25.03o V.I. Ivanov, **V.K. Khe**, V.I. Krylov, D.A. Syrnikov
Far Eastern State Transport University, Khabarovsk, Russia
Optical method for formation of nanostructures in nanosuspension
- V.25.04o **S.O. Gurbatov^{1,2}**, A.A. Kuchmizhak^{1,2}
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
Mapping the refractive index of dielectric surfaces with spherical plasmonic nanoantenna
- V.25.05o **A.N. Galkina¹**, R.V. Romashko^{1,2}, A.A. Sergeev¹, A.A. Leonov²
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
Static and dynamic sorption of free amines on surface of carbon nanotubes modified with nanolayers of polymers
- V.25.06o **K.S. Golokhvast^{1,2}**, V.V. Chaika¹, R.V. Romashko³, A.N. Galkina³,
I.V. Zemchenko¹, A.A. Sergievich¹, A.F. Artemenko¹, E.M. Bulakh⁴,
E.V. Dzubenko¹, I.V. Seredkin^{1,2}
¹*Far Eastern Federal University, Vladivostok, Russia*
²*Pacific Institute of Geography FEB RAS, Vladivostok, Russia*
³*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
⁴*Federal Scientific Center of the East Asia Terrestrial Biodiversity FEB RAS, Russia*
Can plants and fungi cure «the wounds» using silicon gel?

Coffee break**18:30 – 18:50****Poster session II****18:30 – 20:00****Excursion “Night Vladivostok”****20:30 – 23:00**

WHENSDAY, 26 SEPTEMBER

***Excursion to the
Institute of Automation and Control Processes FEB RAS*** ***09:00 – 12:00***

Lunch (FEFU campus) ***12:00 – 13:30***

***Excursion
“Voroshilov’s battery of Russky Island” and
“Primorsky Aquarium”*** ***13:30 – 19:00***

THURSDAY, 27 SEPTEMBER

Plenary session **09:00 – 10:20** Chairman: I. Terai

- PS.27.01i **T.S. Shamirzaev**
Rzhanov Institute of Semiconductor Physics of SB RAS, Novosibirsk, Russia
Exciton recombination and spin dynamics in indirect band gap heterostructures
- PS.27.02i Y. Huang¹, Y. Kumazawa², S. Kusazaki², Y. Saito², V. Saxena², K. Konishi³, Y. Kujime³, T. Kato³, K. Tanaka³, **H. Tatsuoka²**
¹*Graduate School of Science and Technology, Shizuoka University, Hamamatsu, Japan*
²*Graduate School of Integrated Science and Technology, Shizuoka University, Hamamatsu, Japan*
³*Faculty of Engineering, Shizuoka University, Hamamatsu, Japan*
Morphological and structural modifications of Si-based nanostructures synthesized from metal silicide templates in IP6, acid and metal chloride solutions

Coffee break ***10:20 – 10:40***

**Nanostructured coverages, nanocomposites,
functional hybrid materials: formation,
structure and properties** **10:40 – 12:40** Chairman: T.S. Shamirzaev

- VI.27.01o **V.V. Khovaylo**, A.A. Usenko, A.I. Voronin
National University of Science and Technology “MISIS”, Moscow, Russia
Impact of nanoinclusions on thermoelectric properties of skutterudites and SiGe alloys
- VI.27.02o M.M. Mikhailov¹, **V.V. Neshchimenko²**, Chundong Li³
¹*Tomsk State University of Control Systems and Radio-electronics, Tomsk, Russia*
²*Amur State University, Blagoveshchensk, Russia*
³*Harbin Institute of Technology, Harbin, China*
Effect of the surface morphology of zinc oxide particles on their radiation stability

- VI.27.03o **A.S. Gnedenkov¹**, S.L. Sinebryukhov¹, D.V. Mashtalyar^{1,2}, V.S. Egorkin^{1,2}, I.E. Vyaliy¹, S.V. Gnedenkov^{1,2}
¹*Institute of Chemistry FEB RAS, Vladivostok, Russia*
²*Far East Federal University, Vladivostok, Russia*
 Anticorrosion PEO-coating as the effective way of aluminum alloys protection
- VI.27.04o **A.B. Podgorbunsky¹**, T.F. Antokhina¹, N.N. Savchenko¹, A.A. Sokolov², S.L. Sinebryukhov¹, S.V. Gnedenkov¹
¹*Institute of Chemistry FEB RAS, Vladivostok, Russia*
²*Far East Federal University, Vladivostok, Russia*
 Properties of a new superionic compounds (NH₄)₆LiZr_{4-n}Hf_nF₂₃ (n=1, 3)
- VI.27.05o **D.P. Opra¹**, S.V. Gnedenkov^{1,2}, S.L. Sinebryukhov¹, A.A. Sokolov^{1,2}
¹*Institute of Chemistry FEB RAS, Vladivostok, Russia*
²*Far East Federal University, Vladivostok, Russia*
 Doped TiO₂(B) as high performance anode for lithium storage: strategy and principles
- VI.27.06o V.S. Egorkin^{1,2}, **I.E. Vyaliy¹**, N.S. Svirirdov², A.N. Minaev^{1,2}, S.L. Sinebryukhov¹, S.V. Gnedenkov¹
¹*Institute of Chemistry FEB RAS, Vladivostok, Russia*
²*Far East Federal University, Vladivostok, Russia*
 Formation and electrochemical properties of the hydrophobic composite coatings on aluminum alloy
- VI.27.07o **N.B. Kondrikov¹**, P.L. Titov¹, S A. Shegoleva¹, A.S. Lapina¹, V.G. Kuryavyi², M.A. Khorin¹, A.K. Runov¹
¹*Far Eastern Federal University, Vladivostok, Russia*
²*Institute of Chemistry FEB RAS, Vladivostok, Russia*
 The preparation, self-organisation and properties of nanostructured metal-oxidizing coatings formed by anodic oxidation
- VI.27.08o **V.S. Rudnev^{1,2}**, I.V. Lukiyanichuk¹, M.S. Vasilyeva^{1,2}, A.A. Zvereva¹
¹*Institute of Chemistry FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
 Thermally stimulated transformation of the surface nanoarchitecture of Ni-and Cu-doped oxide coatings on titanium

Lunch

12:40 – 14:10

Chairman: X. F. Han

Plenary session

14:10 – 15:30

- PS.27.03i **E.B. Modin**
CIC nanoGUNE Consolider, San Sebastian, Spain
 Advanced three-dimensional electron microscopy characterization of nanomaterials

- PS.27.04i **V.U. Nazarov**¹, V.M. Silkin^{2,3,4}, E.E. Krasovskii^{2,3,4}
¹Research Center for Applied Sciences, Academia Sinica, Taipei 11529, Taiwan
²Departamento de Física de Materiales, Facultad de Ciencias Químicas, Universidad del País Vasco/Euskal Herriko Unibertsitatea, San Sebastián/Donostia, Basque Country, Spain
³List Donostia International Physics Center (DIPC), San Sebastián/Donostia, Basque Country, Spain
⁴Ikerbasque, Basque Foundation for Science, Bilbao, Spain
 Electron energy-loss spectroscopy of quasi-two-dimensional crystals: beyond the energy-loss functions formalism

Formation and properties of ferromagnetic and ferroelectric materials, a spintronics optoelectronics and electromechanics

Chairman: Y.K. Kim

15:30 – 17:15

- IV.27.01o **R.G. Burkovsky**¹, D.A. Andronikova², I.A. Bronwald¹, M.A. Kniazeva¹, A.V. Filimonov¹
¹Peter the Great Saint-Petersburg Polytechnic University, St.-Petersburg, Russia
²Ioffe Institute, St.-Petersburg, Russia
 Structure of incommensurate phases in antiferroelectrics PbZrO₃ and PbHfO₃ at high pressures
- IV.27.02o **E.V. Pustovalov**, A.N. Ferdorets, E.B. Modin, V.V. Tkachev, V.S. Plotnikov
 Far Eastern Federal University, Vladivostok, Russia
 3D structure of thin films by means of focal series
- IV.27.03o **A.S. Samardak**¹, A.G. Kolesnikov¹, A.V. Ognev¹, L.A. Chebotkevich¹, A.V. Sadovnikov^{2,3}, S.A. Nikitov^{2,3}, Y.J. Kim⁴, I.H. Cha⁴, Y.K. Kim⁴
¹Laboratory of thin film technologies, School of Natural Sciences, Far Eastern Federal University, Vladivostok, Russia
²Laboratory "Metamaterials", Saratov State University, Saratov, Russia
³Kotel'nikov Institute of Radioengineering and Electronics, Russian Academy of Sciences, Moscow, Russia
⁴Department of Materials Science and Engineering, Korea University, Seoul, Korea
 Additive chiral interaction on interfaces of "heavy metal/ferromagnet" structures for enhancement of the Dzyaloshinskii–Moriya interaction
- IV.27.04o **M.E. Steblyi**, A.G. Kolesnikov, A.V. Ognev, A.S. Samardak, A.V. Davydenko, L.A. Chebotkevich
 Far Eastern Federal University, Vladivostok, Russia
 Influence of W layer on spin-orbit torques in Ru/Co/Ru films
- IV.27.05o **T.A. Pisarenko**^{1,2}, V.V. Balashev^{1,2}, V.V. Korobtsov^{1,2}, A.A. Dimitriev^{1,2}, V.A. Vikulov¹
¹Institute of Automation and Control processes FEB RAS, Vladivostok, Russia
²Far Eastern Federal University, Vladivostok, Russia
 The lateral photovoltaic effect in Fe/SiO₂/Si structure with different silicon conductivity type
- IV.27.06o **N.I. Plusnin**
 Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia
 Wetting layer and formation of metal - semiconductor interface

IV.27.07o **A.V. Davydenko**¹, A.G. Kozlov¹, V.P. Berdnikov¹, G.S. Suslin¹, M.E. Stebliy¹,
A.V. Ognev¹, A.S. Samardak¹, A.V. Sadovnikov^{2,3}, S.A. Nikitov^{2,3},
L.A. Chebotkevich¹
¹*Far Eastern Federal University, Vladivostok, Russia*
²*Laboratory “Metamaterials”, Saratov State University, Saratov, Russia*
³*Kotel'nikov Institute of Radioengineering and Electronics, Russian Academy of Sciences,
Moscow, Russia*
Tuning of Dzyaloshinskii-Moriya interaction and magnetic structure in
symmetric crystalline [Co/Pd(111)]_n superlattices by variation of Co
thickness

Coffee break ***17:15 – 18:00***

Award ceremony and closing remarks ***18:00 – 19:00***

Symposium Dinner (Café of FEFU) ***19:30 – 21:30***

FRIDAY, 28 SEPTEMBER

Participants departure ***09:00 – 22:00***

POSTER SESSION I, 24 SEPTEMBER

- I.24.01p **N.V. Denisov¹**, A.V. Matetskiy¹, O.A. Utas¹, V.G. Kotlyar¹, D.V. Gruznev¹, L.V. Bondarenko¹, A.Y. Tupchaya¹, A.N. Mihalyuk^{1,2}, A.V. Zotov^{1,3}, A.A. Saranin^{1,2}
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
³*Vladivostok State University of Economics and Service, Vladivostok, Russia*
 Study of atomic and electronic structure of Si(100) $\sqrt{2}\times\sqrt{2}$ -(Au/Tl) surface reconstruction
- I.24.02p **K.V. Ignatovich**
Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia
 Second-Harmonic Generation from bismuth on Si(111) surface
- I.24.03p **K.V. Ignatovich**
Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia
 Investigation of initial stages of growth Pb on Si(111) surface by second harmonic generation
- I.24.04p **N.V. Denisov¹**, A.A. Alekseev¹, O.A. Utas¹, **S.G. Azatyan¹**, A.V. Zotov^{1,2,3}, A.A. Saranin^{1,2}
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*School of Natural Sciences, Far Eastern Federal University, Vladivostok, Russia*
³*Vladivostok State University of Economics and Service, Vladivostok, Russia*
 Bismuth-indium surface compounds on Si(111) and their modification with sodium
- I.24.05p **E.P. Kitsyuk¹**, E.A. Lebedev², A.S. Nartov¹, **R.M. Ryazanov¹**, A.A. Shamanaev³
¹*Scientific-manufacturing company "Technological Centre", Zelenograd, Moscow, Russia*
²*National Research University of Electronic Technology, Zelenograd, Moscow, Russia*
³*Institute of Nanotechnology of Microelectronics of the RAS, Moscow, Russia*
 Improvement of electron field emission from carbon nanotubes by Ba(NO₃)₂ treatment
- I.24.06p **M.V. Ivanchenko^{1,2}**, E.A. Borisenko¹, M.V. Ryzhkova¹, D.A. Tsukanov^{1,2}
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
 Conductivity study of initial stages of β -PdBi₂ formation on Bi/Si(111)
- I.24.07p **M.V. Ryzhkova¹**, D.A. Tsukanov^{1,2}, E.A. Borisenko¹, M.V. Ivanchenko^{1,2}
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
 Study of sodium adsorption on Pb/Si(111) surfaces
- I.24.08p **A.M. Ziatdinov¹**, P.G. Skrylnik¹, V.G. Makotchenko²
¹*Institute of Chemistry FEB RAS, Vladivostok, Russia*
²*Nikolaev Institute of Inorganic Chemistry of SB RAS, Novosibirsk, Russia*
 Films of reduced graphene oxide with percolation nets of nanographenes
- I.24.09p **T.V. Utas¹**, D.A. Olyanich¹, V.V. Mararov^{1,2}, A.V. Zotov^{1,2,3}, A.A. Saranin^{1,2}
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*School of Natural Sciences, Far Eastern Federal University, Vladivostok, Russia*
³*Department of Electronics, Vladivostok State University of Economics and Service, Vladivostok, Russia*
 Fullerene trilliumene on Pb/Si(111) surface

- I.24.10p **D.A. Olyanich¹**, V.V. Mararov¹, T.V. Utas¹, A.V. Zotov^{1,2}, A.A. Saranin^{1,2}
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
Granular C₆₀ layer on Si(111)-Ti surface
- I.24.11p I.A. Tarasov¹, **T.E. Smolyarova^{1,2}**, I.A. Yakovlev¹, A.V. Lukyanenko^{1,2},
S.A. Lyaschenko¹, I.V. Nemtsev¹
¹*Kirensky Institute of Physics of SB RAS, Krasnoyarsk, Russia*
²*Siberian Federal University, 79 Svobodny Pr., Krasnoyarsk 630041, Russia*
Hybrid Au-Fe crystalline nanoparticles obtained by MBE
- III.24.01p **D.V. Fomin¹**, V.L. Dubov¹, K.N. Galkin², N.G. Galkin², S.A. Pyachin³,
A.A. Burkov³
¹*Amur State University, Blagoveshchensk, Russia*
²*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
³*Institute of Materials Science FEB RAS, Khabarovsk, Russia*
The formation and crystalline properties of thin BaSi₂ films obtained by Ba and Si co-deposition and annealing on a Si(111) substrate
- III.24.02p **M.A. Visotin^{1,2}**, I.A. Tarasov¹, A.S. Fedorov^{1,2}, S.G. Ovchinnikov^{1,2}
¹*Kirensky Institute of Physics SB RAS, Krasnoyarsk, Russia*
²*Siberian Federal University, Krasnoyarsk, Russia*
The role of surface energy in α -FeSi₂ nanocrystal orientation on Si(001): density functional study
- III.24.03p **N.G. Galkin^{1,2}**, K.N. Galkin¹, I.M. Chernev¹, D.L. Goroshko^{1,2}, E.A. Chusovitin¹,
A.V. Shevlyagin¹, A.A. Usenko³, V.V. Khovaylo³
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
³*National University of Science and Technology, Moscow, Russia*
Comparison of the structural, optical and thermoelectrical properties of Ca silicide films with variable composition on Si substrates
- III.24.04p **A.S. Gouralnik¹**, S.V. Chusovitina¹, S.A. Dotsenko¹, V.A. Ivanov², I.V. Tkachenko³
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
³*Institute of Chemistry FEB RAS, Vladivostok, Russia*
Magnetism in exchange coupled Fe-Si 3-layers with controlled composition profile
- III.24.05p **S.A. Lyaschenko¹**, O.A. Maximova^{1,2}, D.V. Shevtsov¹, I.A. Yakovlev¹,
I.A. Tarasov¹, S.N. Varnakov¹, S.G. Ovchinnikov^{1,2}
¹*Kirensky Institute of Physics of SB RAS, Krasnoyarsk, Russia*
²*Siberian Federal University, Krasnoyarsk, Russia*
Measurements of the optical and magneto-optical properties of Fe-Si layer structures at different temperatures
- III.24.06p **K.N. Galkin¹**, D.L. Goroshko^{1,2}, E.A. Chusovitin¹, S.A. Dotsenko^{1,2}, N.G. Galkin^{1,2},
A.K. Gutakovskii^{3,4}
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
³*Rzhanov Institute of Semiconductor Physics SB RAS, Novosibirsk, Russia*
⁴*Novosibirsk State University, Novosibirsk, Russia*
Formation of α -FeSi₂ nanorods on Si(111) vicinal surface by solid phase epitaxy

- III.24.07p **I.A. Tarasov¹**, M.A. Visotin^{1,2}, M.N. Volochaev^{1,3}, L.A. Solovyov⁴, A.S. Aleksandrovsky^{1,2}, M.V. Rautskii¹, V.S. Zhandun¹, I.A. Yakovlev¹, I.V. Nemtsev¹, S.N. Varnakov¹, S.G. Ovchinnikov¹
¹Kirensky Institute of Physics, Federal Research Center KSC SB RAS, Krasnoyarsk, Russia
²Siberian Federal University, Krasnoyarsk, Russia
³Siberian State Aerospace University, Krasnoyarsk, Russia
⁴Institute of Chemistry and Chemical Technology, Federal Research Center KSC SB RAS, Krasnoyarsk, Russia
 Tuning the magnetic, transport and optical properties of FeSi₂ nanocrystals
- III.24.08p **N.I. Plusnin**
 Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia
 Epitaxial metallic spin injector for spin-devices with field control channel on silicon substrate: review
- III.24.09p S.V. Dubkov¹, D.G. Gromov¹, **A.I. Savitskiy¹**, A.Yu. Trifonov², Yu.P. Shaman³, A.A. Polokhin³, A.A. Dudin⁴
¹National Research University of Electronic Technology, Moscow, Zelenograd, Russia
²Institute of Physical Problems named after F.V. Lukin, Moscow, Zelenograd, Russia
³SMC «Technological Centre», Moscow, Zelenograd, Russia
⁴Institute of Nanotechnology of Microelectronics of the RAS, Moscow, Russia
 Influence of nanostructures parameters based on Au, Ag, Au-Ag nanoparticles formed by thermal evaporation in vacuum on amplification of the Raman scattering
- III.24.10p E.O. Nashchochin¹, **D.S. Shtarev²**, A.V. Shtareva¹, A.V. Syuy¹
¹Far Eastern State Transport University, Khabarovsk, Russia
²Yu.A. Kosygin Institute of Tectonics and Geophysics Far Eastern Branch, Russian Academy of Sciences, Khabarovsk, Russia
 Strontium bismuthates Sr₂Bi₂O₅ and Sr₆Bi₂O₁₁: temperature dependencies of Urbach energy and location of «Urbach focus»
- III.24.11p **D.A. Shashura¹**, Yu.O. Privar¹, A.V. Pestov², E.B. Modin¹, S.Yu. Bratskaya¹
¹Institute of Chemistry Far Eastern Branch of RAS, Vladivostok, Russia
²I. Ya. Postovsky Institute of Organic Synthesis, Ural Branch of RAS, Yekaterinburg, Russia
 Metal-affine sorbents based on cryogels of carboxyalkyl chitosan derivatives for fluoroquinolones uptake
- III.24.12p **A.M. Maslov^{1,2}**, N.I. Plusnin¹
¹Institute for Automation and Control Processes, 5 Radio St., Vladivostok 690041, Russia
²Far Eastern Federal University, 8 Sukhanova St., Vladivostok 690950, Russia
 Evolution of optical spectra at the initial stages of Fe growth on Si(001)
- III.24.13p **O.V. Volovlikova¹**, S.A. Gavrilov¹, G.O. Silakov¹, A.A. Polokhin², Yu.P. Shaman², A.A. Dudin³, A.V. Zheleznyakova¹
¹National Research University of Electronic Technology (MIET), Zelenograd, Moscow, Russia
²Scientific-Manufacturing Complex «Technological Centre» MIET, Zelenograd, Moscow, Russia
³Institute of Nanotechnology of Microelectronics, Russian Academy of Sciences, Moscow, Russia
 The synthesis of the porous silicon powder by Pd-assisted chemical etching

- III.24.14p **D.A. Smolyakov**¹, N.V. Volkov¹, A.N. Masyugin², A.S. Tarasov¹, M.V. Rautskii¹, A.V. Lukyanenko¹, M.N. Volochaev^{1,2}, I.A. Yakovlev^{1,2}
¹Kirensky Institute of Physics, Krasnoyarsk, Russia
²Reshetnev Siberian State University of Science and Technology, Krasnoyarsk, Russia
Investigation of silicon-based hybrid structures of different composition
- III.24.15p **O.M. Orlov**
JSC "Research Institute of Molecular Electronics", Moscow, Zelenograd, Russia
Promising materials of nonvolatile memory based on HfO_x and achievement of device parameters in the TiN/Hf_{0.5}Zr_{0.5}O₂/TiN/SiO₂/Si and TiN/Hf_xAl_{1-x}O_y/Pt/SiO₂/Si test structures obtained on the national technological basis
- V.24.01p **A.V. Syuy**¹, A.A. Gabain², N.A. Teplyakova², N.V. Sidorov², M.N. Palatnikov²
¹Far Eastern State Transport University, Khabarovsk, Russia
²Tananaev Institute of Chemistry and Technology of the Federal Research Centre "Kola Science Centre of the Russian Academy of Sciences», Apatity, Russia
Kinetic dependencies of the photorefractive effect in lithium niobate crystals
- V.24.02p **K.R. Karimullin**^{1,2}, A.I. Arzhanov^{1,2}, A.V. Naumov^{1,2}
¹Institute for Spectroscopy RAS, Troitsk, Moscow, Russia
²Moscow State Pedagogical University, Moscow, Russia
Low temperature photon echo spectroscopy of nanocomposites with semiconductor colloidal quantum dots
- V.24.03p M.M. Mikhailov¹, **V.V. Neshchimenko**², A.V. Grigorevsky³, A.A. Lovitskiy¹, I.S. Vashchenkov³
¹Tomsk State University of Control Systems and Radio-electronics, Tomsk, Russia
²Amur State University, Blagoveshchensk, Russia
³AO "Kompozit", Moscow, Russia
On the radiation stability of BaSO₄ pigment modified with SiO₂ nanoparticles and applied for spacecraft thermal control coatings
- V.24.04p **E.V. Mitsai**¹, A.A. Kuchmizhak^{1,2}
¹Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia
²Far Eastern Federal University, Vladivostok, Russia
Non-invasive temperature-feedback SERS with all-dielectric resonant nanostructures
- V.24.05p **D.V. Pavlov**^{1,2}, A.A. Kuchmizhak^{1,2}
¹Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia
²Far Eastern Federal University, Vladivostok, Russia
Laser-printed self-organized bimetallic nanotextures for multiwavelength surface enhanced photoluminescence
- V.24.06p R.V. Romashko^{1,2}, **M.A. Asalkhanova**¹
¹Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia
²Far Eastern Federal University, Vladivostok, Russia
Recording of dynamic holograms in photorefractive crystals CdTe by bichromatic radiation

- V.24.07p **S.A. Syubaev^{1,2}**, A.A. Kuchmizhak^{1,2}, A.P. Porfirev³
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
³*Samara National Research University, Samara, Russia*
 Designing spiral-shape beams to tailor chirality of laser-printed nanoneedles
- V.24.08p V.I. Ivanov, **O.O. Ovseychuk**
Far Eastern State Transport University, Khabarovsk, Russia
 The nonlinear optical properties of the vanadium dioxide films
- V.24.09p **K.A. Sergeeva¹**, A.A. Sergeev^{1,2}, I.V. Postnova¹, S.S. Voznesenskiy^{1,2}
¹*Far Eastern Federal University, Vladivostok, Russia*
²*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
 ZnS:Mn²⁺ quantum dots as efficient photocatalyst for organic dye degradation
- V.24.10p V.I. Ivanov, **A.V. Myagotin**, G.D. Ivanova
Far Eastern State Transport University, Khabarovsk, Russia
 Thermal lens method of the diagnostics of liquid nanomaterials
- V.24.11p M.V. Tutov¹, A.Yu. Mironenko², **A.A. Sergeev³**, A.A. Leonov^{1,3}, S.Yu. Bratskaya²
¹*Far Eastern Federal University, Vladivostok, Russia*
²*Institute of Chemistry FEB RAS, Vladivostok, Russia*
³*Institute for Automation and Control Processes FEB RAS, Vladivostok, Russia*
 Highly sensitive luminescent sensor complexes for selective detection of gold ions in aqueous media
- V.24.12p **K.S. Golokhvast¹**, A.V. Fedorov², A.I. Korobeev¹, A.I. Kamko³, A.S. Smirnov¹, I.V. Zemchenko¹, A.A. Sergievich¹, A.F. Artemenko¹, V.V. Chernyshev¹, V.V. Chaika¹
¹*Far Eastern Federal University, Vladivostok, Russia*
²*Institute of Legislation and Comparative Law under the Russian Federation Government, Moscow, Russia*
³*Khabarovsk Department of Internal Affairs, Khabarovsk city, Russia*
 Microparticles of silicon oxide (phytoliths) found in Cannabis sativa from Khabarovsk Krai (Russia)
- V.24.13p **K.S. Golokhvast^{1,2}**, V.V. Chaika¹, A.M. Zakharenko¹, A.A. Sergievich¹, I.V. Zemchenko¹, A.F. Artemenko¹, I.V. Seryodkin²
¹*Far Eastern federal University, Vladivostok, Russia*
²*Pacific Geographical Institute FEB RAS, Vladivostok, Russia*
 Hexagonal microparticles of silicon oxide (phytolites) from red algae Tichocarpus crinitus
- V.24.14p Yu.N. Kulchin¹, **O.V. Nakonechnaya²**, I.V. Gafitskaya², O.V. Grishchenko², T.Yu. Epifanova², I.Yu. Orlovskaya², Yu.N. Zhuravlev², E.P. Subbotin¹
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Federal Scientific Center of the East Asia Terrestrial Biodiversity, Vladivostok, Russia*
 Plant morphogenesis under different light

V.24.15p Yu.N. Kulchin¹, **A.A Kostyanko**¹, V.N. Zmeeva², E.P. Subbotin¹
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Federal Scientific Center of the East Asia Terrestrial Biodiversity, Vladivostok, Russia*
The effect of multispectral light emitting diodes (LEDs) on the activation
of morphogenic processes in cell culture of rice *Oryza Sativa* L

POSTER SESSION II, 25 SEPTEMBER

- II.25.01p **A.A. Spirina**^{1,2}, I.G. Neizvestny^{1,2}, N.L. Shwartz^{1,2}
¹*Institute of Semiconductor Physics SB RAS, Novosibirsk, Russia*
²*Novosibirsk State Technical University, Novosibirsk, Russia*
Examination of GaAs and InAs Langmuir evaporation by simulation
- II.25.02p **E.Y. Subbotin**¹, D.L. Goroshko^{1,2}, E.A. Chusovitin¹, S.V. Chusovitina¹, S.A. Balagan¹, V.U. Nazarov³, N.G. Galkin^{1,2}
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
³*Research Center for Applied Sciences, Academia Sinica, Taipei 11529, Taiwan*
Formation and temperature stability of GaSb islands on Si(111)
- II.25.03p **S.V. Chusovitina**¹, E.Y. Subbotin¹, E.A. Chusovitin¹, D.L. Goroshko^{1,2}, S.A. Dotsenko^{1,2}, S.A. Pyachin³, I.A. Astapov³, K.N. Galkin¹
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
³*Far Eastern State Transport University, Khabarovsk, Russia*
Formation and temperature stability of GaSb film grown on Si(111) by solid phase epitaxy
- II.25.04p **S.A. Dotsenko**^{1,2}, D.L. Goroshko^{1,2}, E.A. Chusovitin¹, S.A. Kitan¹, K.N. Galkin¹, N.G. Galkin^{1,2}
¹*Institute of Automation and Control processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
Si_{1-x}Sn_x films grown by low-temperature on Si(100) substrate: crystal structure, optical properties and thermal stability
- II.25.05p **S.A. Balagan**¹, D.L. Goroshko^{1,2}, V.U. Nazarov³, N.G. Galkin^{1,2}
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
³*Research Center for Applied Sciences, Academia Sinica, Taipei 11529, Taiwan*
Ab-initio calculation of phonon spectrum and thermal conductivity of Si with embedded GaSb nanocrystals
- II.25.06p N.G. Galkin¹, **D.T. Yan**², K.N. Galkin¹, E.A. Chusovitin¹, M.V. Bozhenko¹
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern State Transport University, Khabarovsk, Russia*
Comparative analysis of the effect of immersion of porous silicon in solutions of LiBr and Fe(NO₃)₃ on the stability and intensity of its photoluminescence
- II.25.07p **A.V. Lukyanenko**^{1,2}, A.S. Tarasov^{1,2}, I.A. Bondarev^{1,2}, M.V. Rautskii¹, T.E. Smolyarova^{1,2}, A.N. Masyugin³, F.V. Zelenov², I.A. Yakovlev¹, S.N. Varnakov¹, S.G. Ovchinnikov^{1,2}, N.V. Volkov¹
¹*Kirensky Institute of Physics, Federal Research Center KSC SB RAS, Krasnoyarsk, Russia*
²*Institute of Engineering Physics and Radio Electronics, Siberian Federal University, Krasnoyarsk, Russia*
³*Reshetnev Siberian State University of Science and Technology, Krasnoyarsk, Russia*
Silicon nanowire field-effect transistors. Technology and characterization

- II.25.08p **D.L. Goroshko**^{1,2}, N.G. Galkin^{1,2}, E.A. Chusovitin¹, S.A. Kitan¹, E.Y. Subbotin¹, A.V. Tupkalo¹
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
 Photoconductivity and conductivity processes in Si-Sn films grown on Si(100) substrate at room temperature
- IV.25.01p **A.G. Kolesnikov**, M.E. Steblyi, A.V. Ognev, A.S. Samardak, L.A. Chebotkevich
Far Eastern Federal University, Vladivostok, Russia
 Nucleation, stability and current induced motion of skyrmionium
- IV.25.02p **I.G. Iliushin**, S.V. Anisimov, L.L. Afremov
Far Eastern Federal University, Vladivostok, Russia
 The oxidation effect on the blocking temperature and magnetic characteristics of nanosized magnetite particles
- IV.25.03p D.S. Neznakhin¹, **G.A. Politova**^{2,3}, L.A. Ivanov³, M.A. Paukov^{4,5}, E.A. Tereshina-Chitrova⁶, D.I. Gorbunov⁷, I.S. Tereshina³, N.V. Kudrevatykh¹
¹*Institute of Natural Sciences, Ural Federal University, Yekaterinburg, Russia*
²*Baikov Institute of Metallurgy and Materials Science RAS, Moscow, Russia*
³*Lomonosov Moscow State University, Faculty of Physics, Moscow, Russia*
⁴*Charles University, Faculty of Mathematics and Physics, Prague, Czech Republic*
⁵*Immanuel Kant Baltic Federal University, Kaliningrad, Russia*
⁶*Institute of Physics, ASCR, 18221, Prague, Czech Republic*
⁷*Dresden High Magnetic Field Laboratory (HLD-EMFL), Helmholtz-Zentrum Dresden-Rossendorf, D-01314 Dresden, Germany*
 Low-temperature magnetic hysteresis in Nd (Pr)-Fe-B nanostructured alloys with 2-14-1 type main phase composition
- IV.25.04p **A.Yu. Samardak**¹, A.V. Ognev¹, A.G. Kolesnikov¹, M.E. Steblyi¹, A.V. Gerasimenko², L.A. Chebotkevich¹, A.S. Samardak¹
¹*Far Eastern Federal University, Vladivostok, Russia*
²*Institute of Chemistry FEB RAS, Vladivostok, Russia*
 Effect of annealing on magnetic properties and the interfacial Dzyaloshinskii-Moriya interaction of Ru/Co/W/Ru films
- IV.25.05p **O.A. Maximova**^{1,2}, S.A. Lyaschenko¹, D.V. Shevtsov¹, I.A. Yakovlev¹, S.G. Ovchinnikov^{1,2}
¹*Kirensky Institute of Physics of SB RAS, Krasnoyarsk, Russia*
²*Siberian Federal University, Krasnoyarsk, Russia*
 Development of techniques for processing data from magneto-ellipsometry measurements
- IV.25.06p **E.V. Pustovalov**, A.N. Ferdorets, V.V. Tkachev, V.S. Plotnikov
Far Eastern Federal University, Vladivostok, Russia
 Atomic ordering and disordering of amorphous CoP alloy
- IV.25.07p **T.A. Pisarenko**^{1,2}, V.V. Balashev^{1,2}, V.V. Korobtsov^{1,2}, A.A. Dimitriev^{1,2}, V.A. Vikulov¹
¹*Institute of Automation and Control Processes FEB RAS, Vladivostok, Russia*
²*Far Eastern Federal University, Vladivostok, Russia*
 The lateral photovoltaic effect in Fe₃O₄/SiO₂/p-Si structure

- IV.25.08p **N.V. Ilin**, V.V. Tkachev, A.M. Frolov, V.A. Ivanov, A.S. Kuchma, G.S. Kraynova, V.S. Plotnikov
Far Eastern Federal University, Vladivostok, Russia
Structure and properties features of amorphous iron-based metal foils with different copper contents
- IV.25.09p **V.V. Tkachev**, A.K. Tsesarskaya, A.N. Fedorets, D.A. Polyanskii, G.S. Kraynova, V.S. Plotnikov
Far Eastern Federal University, Vladivostok, Russia
Phase structure features of amorphous iron-based metal foils with different copper contents
- IV.25.10p **V.Yu. Samardak**¹, A.V. Ognev¹, A.Yu. Samardak¹, A. S. Noshahr², F. Nasirpour², A.S. Samardak¹
¹*School of Natural Sciences, Far Eastern Federal University, Vladivostok, Russia*
²*Faculty of Materials Engineering, Sahand University of Technology, Tabriz, Iran*
Temperature dependent magnetic properties and FORC probing of NiMn nanowire arrays
- IV.25.11p A.Yu. Samardak, **A.V. Ognev**, A.G. Kolesnikov, M.E. Steblyi, A.S. Samardak, E.V. Pustovalov, L.A. Chebotkevich
Far Eastern Federal University, Vladivostok, Russia
Ion beam irradiation induced modification of perpendicular magnetic anisotropy and domain structure in layered films
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VI.25.15p **M.I. Dvornik**, E.A. Mikhailenko

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Fabrication of nanostructured gradient tungsten-cobalt alloy using
carbon deficiency powder

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